

isc N-Channel MOSFET Transistor

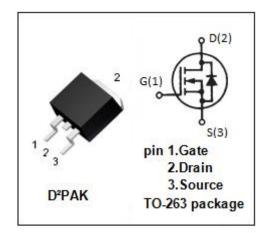
IXTA50N20P

• FEATURES

- Static drain-source on-resistance:
 R_{DS}(on) ≤ 60mΩ
- Fully characterized avalanche voltage and current
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATION

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

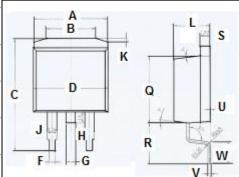


• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	200	V
V _{GS}	Gate-Source Voltage	±20	V
ID	Drain Current-Continuous	50	А
I _{DM}	Drain Current-Single Pulsed	120	Α
P _D	Total Dissipation @Tc=25℃	360	W
Tj	Operating Junction Temperature	-55~175	$^{\circ}$
T _{stg}	Storage Temperature	-55~125	$^{\circ}$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th(j-c)}	Junction-to-case thermal resistance	0.42	°C/W



	mm		
DIM	MIN	MAX	
Α	10		
В	6.6	6.8	
C	15.23	15.25	
D	10.15	10.17	
F	0.76	0.78	
G	1.26	1.28	
Н	1.4	1.6	
J	1.33	1.35	
K	0.4	0.6	
L	4.6	4.8	
0	8.69	8.71	
R	5.28	5.30	
S	1.26	1.28	
U	0.0	0.2	
V	0.37	0.39	
W	2.80	2.82	



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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; ID =250 μ A	200		V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} ; ID =250 μ A	2.5	5.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D = 50A		60	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} =0V		±100	nA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = V _{DSS} ; V _{GS} = 0V		25	- μΑ
		V _{DS} = V _{DSS} ; V _{GS} = 0V;T _J =150°C		250	
V _{SD}	Diode forward voltage	I _F = 50A; V _{GS} = 0V		1.5	V



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